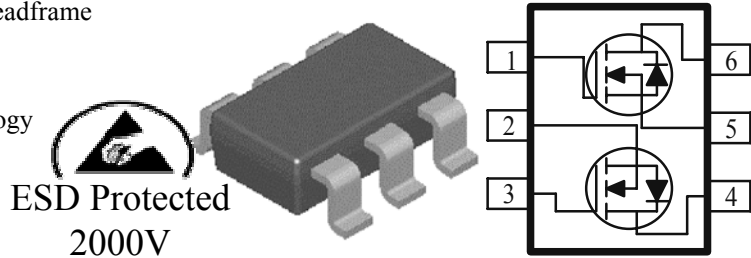


N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low $r_{DS(on)}$ provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe TSOP-6 saves board space
- Fast switching speed
- High performance trench technology

| PRODUCT SUMMARY | | |
|-----------------|----------------------------|-----------|
| V_{DS} (V) | $r_{DS(on)}$ m(Ω) | I_D (A) |
| 30 | 63 @ $V_{GS}=4.5V$ | 3.5 |
| | 82 @ $V_{GS}=2.5V$ | 3.3 |



| ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ UNLESS OTHERWISE NOTED) | | | | |
|---|------------------|----------------|------------|------------|
| Parameter | | Symbol | Limit | Units |
| Drain-Source Voltage | | V_{DS} | 30 | V |
| Gate-Source Voltage | | V_{GS} | ± 12 | |
| Continuous Drain Current ^a | $T_A=25^\circ C$ | I_D | 3.5 | A |
| | $T_A=70^\circ C$ | | 2.8 | |
| Pulsed Drain Current ^b | | I_{DM} | 16 | |
| Continuous Source Current (Diode Conduction) ^a | | I_S | 1.25 | A |
| Power Dissipation ^a | $T_A=25^\circ C$ | P_D | 1.3 | W |
| | $T_A=70^\circ C$ | | 0.8 | |
| Operating Junction and Storage Temperature Range | | T_J, T_{stg} | -55 to 150 | $^\circ C$ |

| THERMAL RESISTANCE RATINGS | | | | |
|--|-----------------|-----------------|---------|--------------|
| Parameter | | Symbol | Maximum | Units |
| Maximum Junction-to-Ambient ^a | $t \leq 10$ sec | $R_{\theta JA}$ | 100 | $^\circ C/W$ |
| | Steady-State | | 166 | $^\circ C/W$ |

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

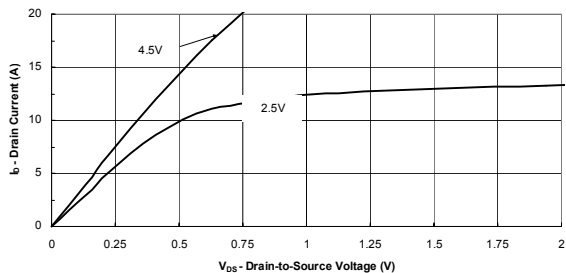
| SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED) | | | | | | |
|---|---------------------|---|--------|-----|------|------|
| Parameter | Symbol | Test Conditions | Limits | | | Unit |
| | | | Min | Typ | Max | |
| Static | | | | | | |
| Gate-Threshold Voltage | V _{GS(th)} | V _{DS} = V _{GS} , I _D = 250 uA | 0.7 | | | V |
| Gate-Body Leakage | I _{GSS} | V _{DS} = 0 V, V _{GS} = 4 V | | | ±100 | nA |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} = 24 V, V _{GS} = 0 V | | | 1 | uA |
| | | V _{DS} = 24 V, V _{GS} = 0 V, T _J = 55°C | | | 25 | |
| On-State Drain Current ^A | I _{D(on)} | V _{DS} = 5 V, V _{GS} = 4.5 V | 6 | | | A |
| Drain-Source On-Resistance ^A | r _{DS(on)} | V _{GS} = 4.5 V, I _D = 3.5 A | | | 63 | mΩ |
| | | V _{GS} = 2.5 V, I _D = 3.3 A | | | 82 | |
| Forward Transconductance ^A | g _{fs} | V _{DS} = 15 V, I _D = 3.5 A | | 6.9 | | S |
| Diode Forward Voltage | V _{SD} | I _S = 2.3 A, V _{GS} = 0 V | | 0.8 | | V |
| Dynamic^b | | | | | | |
| Total Gate Charge | Q _g | V _{DS} = 15 V, V _{GS} = 4.5 V, I _D = 3.5 A | | 6.3 | | nC |
| Gate-Source Charge | Q _{gs} | | | 0.9 | | |
| Gate-Drain Charge | Q _{gd} | | | 1.9 | | |
| Turn-On Delay Time | t _{d(on)} | V _{DD} = 25 V, R _L = 25 Ω, I _D = 1 A, V _{GEN} = 10 V | | 16 | | nS |
| Rise Time | t _r | | | 5 | | |
| Turn-Off Delay Time | t _{d(off)} | | | 23 | | |
| Fall-Time | t _f | | | 3 | | |

Notes

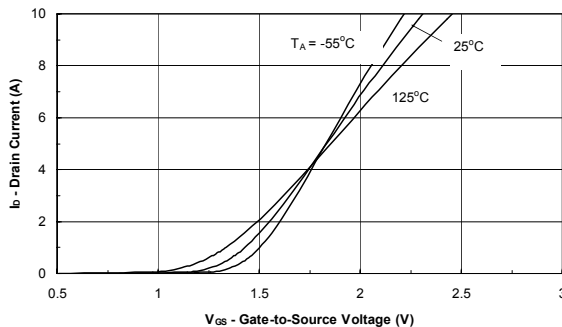
- Pulse test: PW ≤ 300us duty cycle ≤ 2%.
- Guaranteed by design, not subject to production testing.

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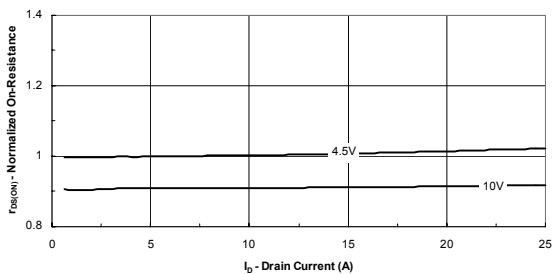
Typical Electrical Characteristics (N-Channel)



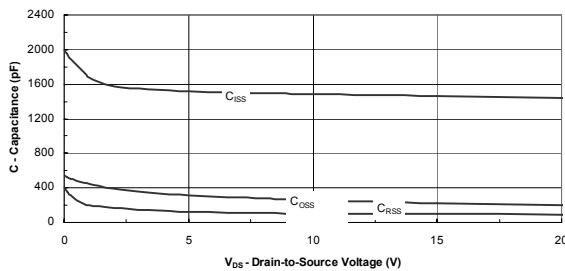
Output Characteristics



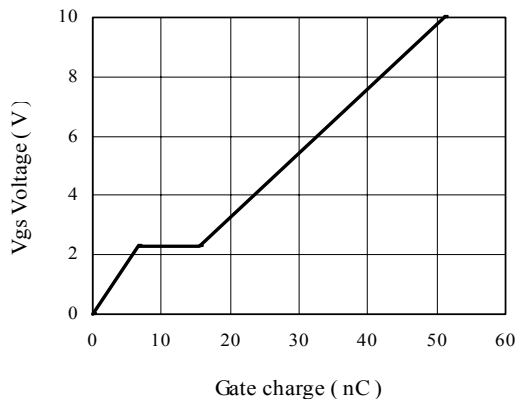
Transfer Characteristics



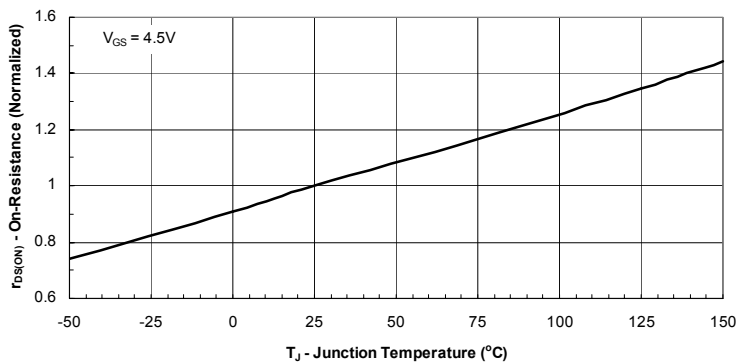
On-Resistance vs. Drain Current



Capacitance

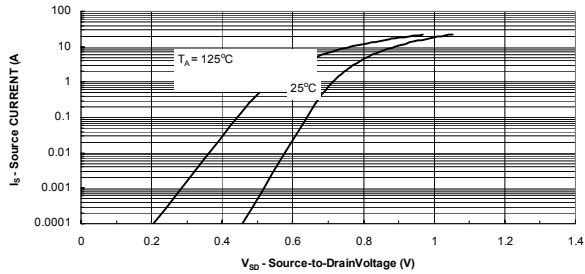


Gate Charge

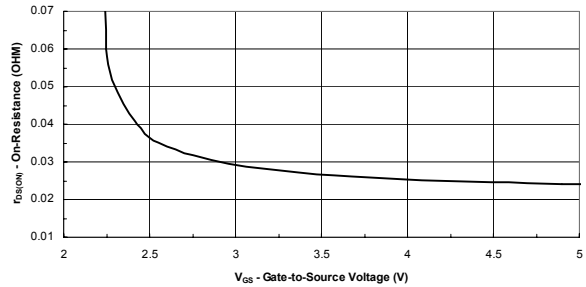


On-Resistance vs. Junction Temperature

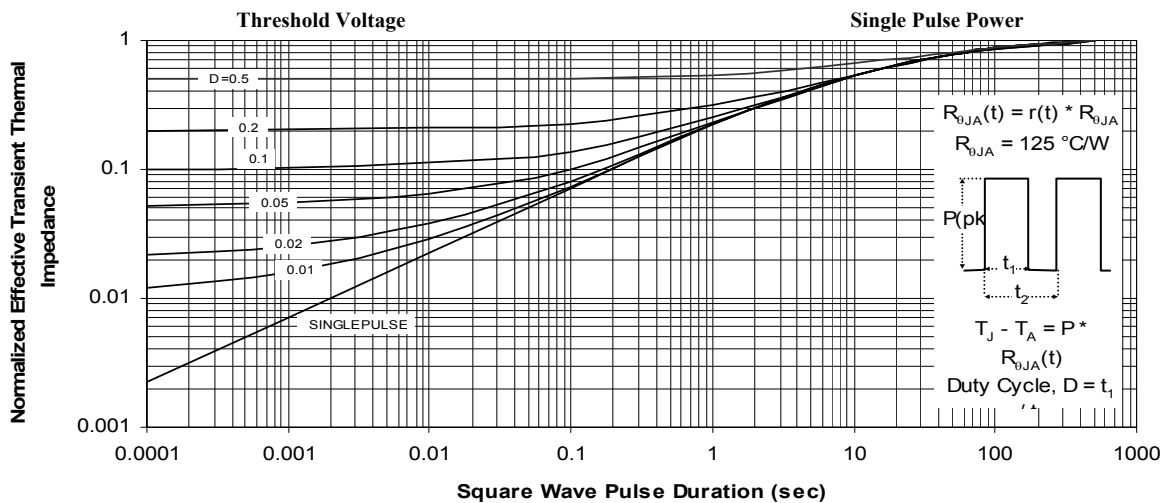
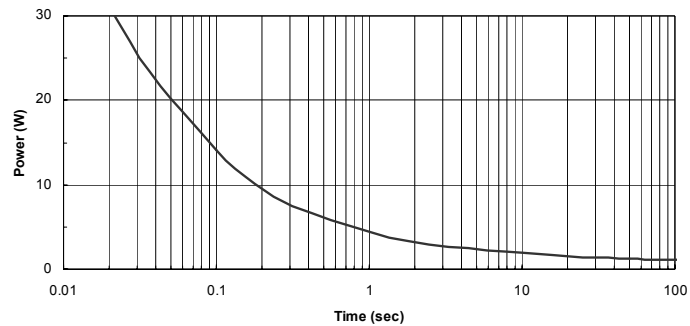
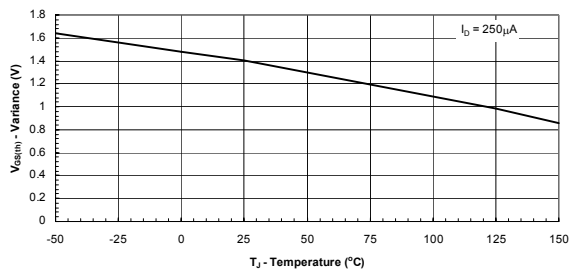
Typical Electrical Characteristics (N-Channel)



Source-Drain Diode Forward Voltage



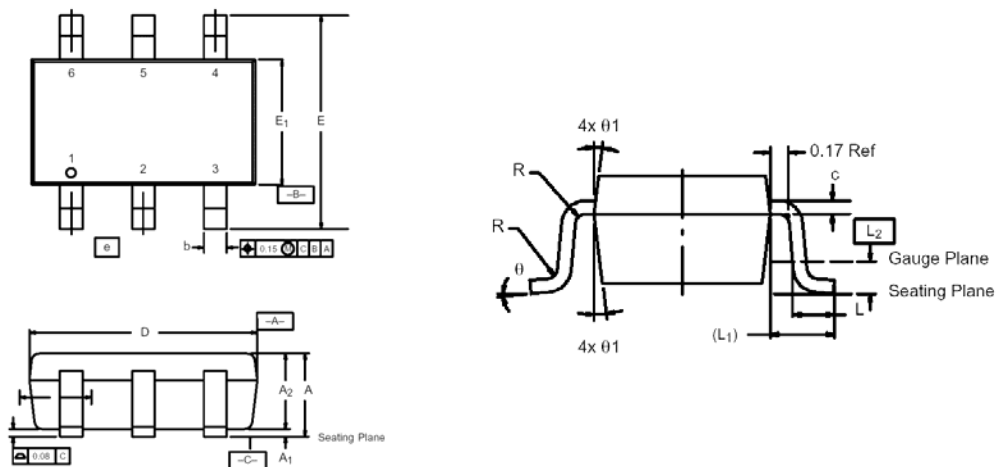
On-Resistance vs. Gate-to-Source Voltage



Normalized Thermal Transient Impedance, Junction-to-Ambient

Package Information

TSOP-6: 6LEAD



| Dim | MILLIMETERS | | | INCHES | | |
|----------------|-------------|------|------|------------|-------|-------|
| | Min | Nom | Max | Min | Nom | Max |
| A | 0.91 | – | 1.10 | 0.036 | – | 0.043 |
| A ₁ | 0.01 | – | 0.10 | 0.0004 | – | 0.004 |
| A ₂ | 0.84 | – | 1.00 | 0.033 | 0.038 | 0.039 |
| b | 0.30 | 0.32 | 0.45 | 0.012 | 0.013 | 0.018 |
| c | 0.10 | 0.15 | 0.20 | 0.004 | 0.006 | 0.008 |
| D | 2.95 | 3.05 | 3.10 | 0.116 | 0.120 | 0.122 |
| E | 2.70 | 2.85 | 2.98 | 0.106 | 0.112 | 0.117 |
| E ₁ | 1.55 | 1.65 | 1.70 | 0.061 | 0.065 | 0.067 |
| e | 1.00 BSC | | | 0.0394 BSC | | |
| L | 0.35 | – | 0.50 | 0.014 | – | 0.020 |
| L ₁ | 0.60 Ref | | | 0.024 Ref | | |
| L ₂ | 0.25 BSC | | | 0.010 BSC | | |
| R | 0.10 | – | – | 0.004 | – | – |
| θ | 0° | 4° | 8° | 0° | 4° | 8° |
| θ ₁ | 7° Nom | | | 7° Nom | | |